



THE DATASHEET OF IP4059CX5/LF,135





Discrete Semiconductors Selection Guide 2010

Diodes, transistors, ESD and signal conditioning devices
Excellence in portfolio and performance



Introducing new package technology

Portable and increasingly smaller end products fuel the race towards more sophisticated functionality in smaller form factors. To support system designers manage this challenge we as NXP develop products that fulfill requirements regarding space constraints, boosted performance and environmental aspects. Have a look at these five new SMD packages that take discretes to the next level:

Leadless powerhouse – SOT1061 and SOT1118

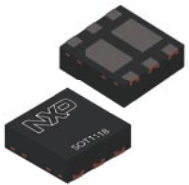
Features

- ▶ Exposed heat sink for excellent thermal and electrical conductivity
- ▶ Power dissipation capability (P_{tot}) of > 1 W
- ▶ Small footprint of 2 x 2 mm and height of 0.65 mm



Products in SOT1061

- 1 and 2 A low V_F Schottky rectifiers, *pages 11 and 12*
- Low V_{CEsat} (BISS) transistors, *pages 57, 59, 64 and 65*



Products in SOT1118

- Small-signal MOSFET P-channel and FET-KYs, *page 77*

FlatPower – SOD123W and SOD128

Features

- ▶ High power ratings due to clip-bonding technology and optimized die design
- ▶ 1 mm low profile, footprint of 2.6 x 1.7 (SOD123W) and 3.8 x 2.5 mm (SOD128)
- ▶ Pad layout compatible with SMA for easy drop-in replacement
- ▶ AEC-Q101 qualified



Products in SOD123W and SOD128

- 400 W and 600 W TVS diodes, *pages 44 and 45*
- 1 to 5 A low V_F Schottky rectifiers, *page 10*

Small, strong, perfectly visible – SOD882D

Features

- ▶ Exposed leads facilitate visual inspection of solder joints
- ▶ More rugged and reliable bond between device and PCB board
- ▶ Reduced height down to 0.37 mm and small footprint of 1 x 0.6 mm



Products in SOD882D

- Standard ESD protection devices, *page 24*

Transfer to halogen-free products

Since 2009 all NXP small-signal discrete SMD packages on the market are “Dark Green”, meaning they are fully RoHS compliant (directive 2002/95/EC) and do not contain halogens or antimony exceeding allowed limits:

Substances	Limit
Antimony Oxides	< 900 ppm
Chlorinated + Brominated Compounds	Σ < 900 ppm

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Products for general applications

Benefit from interactive features in the online edition of this selection guide: A click on a product type takes you to the corresponding product information page on the NXP website. There you'll find data sheets and other design-support documents. To access the online selection guide, go to www.nxp.com/discrete_selection_guide

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Diodes

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Medium power low V_F Schottky rectifiers single ≥ 200 mA

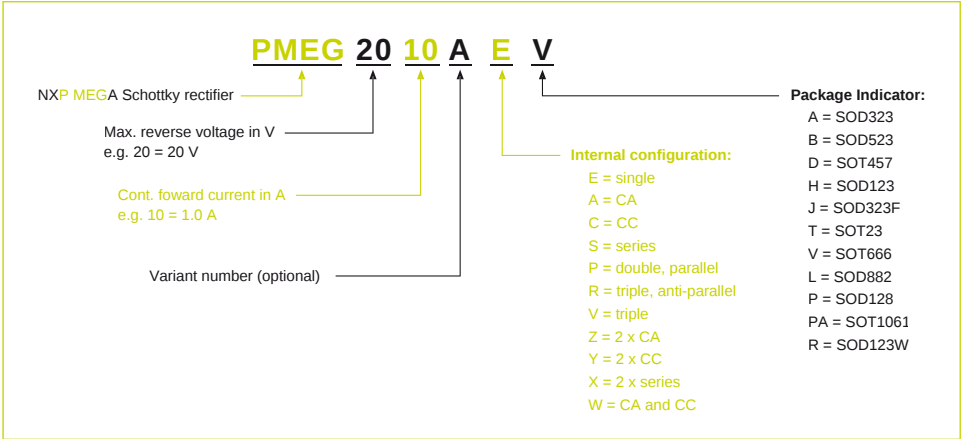
types in **bold** represent new products

I_F max (A)	V_R max (V)	V_F max (mV) @ I_F max	I_R max (mA) @ V_R max	Package	SOD128	SOD87 (Melf)	SOT457 (SC-74)	SOT23	SOD123W		SOD123F	SOT1061	SOT323 (SC-70)	SOD323 (SC-76)	SOD323F (SC-90)	SOT666	SOD523 (SC-79)	SOD882
																		
					Size (mm)	3.8 x 2.5 x 1.0	3.5 x 2.05 x 2.05	2.9 x 1.5 x 1.0	2.9 x 1.3 x 1.0	2.6 x 1.7 x 1.0	2.6 x 1.6 x 1.1	2.0 x 2.0 x 0.65	2.0 x 1.25 x 0.95	1.7 x 1.25 x 0.95	1.7 x 1.25 x 0.7	1.6 x 1.2 x 0.55	1.2 x 0.8 x 0.6	1.0 x 0.6 x 0.5
					P_{tot} (mW) @ 1 cm ²	1050	1000	540	420	950	830	1000	250	570	830	570	450	250
0.2	30	480	0.04	low V_F														
	40	600	0.01	low I_R														
	60	600	0.1	low V_F														
0.5	20	390	0.2	low V_F				PMEG2005ET			PMEG2005EH			PMEG2005AEA	PMEG2005EJ	PMEG2005AEV		
		440	1.5	low V_F														PMEG2005AEL
		480	0.01	low I_R													PMEG2005EB	
		500	0.03	low I_R														PMEG2005EL
	30	430	0.15	low V_F				PMEG3005ET			PMEG3005EH			PMEG3005AEA	PMEG3005EJ	PMEG3005AEV		
		500	0.5	low V_F													PMEG3005EB	PMEG3005EL
	40	470	0.1	low V_F				PMEG4005ET			PMEG4005EH			PMEG4005AEA	PMEG4005EJ	PMEG4005AEV		
		550	0.1	low V_F				BAT720					1PS70SB20					
1.0	20	340	1	low V_F					PMEG2010ER									
		375	1.9	low V_F							PMEG2010EPA							
		430	0.2	low V_F				PMEG2010AET			PMEG2010AEH							
		450	0.05	low I_R					PMEG2010BER									
			1.0	low V_F		PRLL5817												
		500	0.2	low V_F				PMEG2010ET			PMEG2010EH			PMEG2010BEA	PMEG2010EJ	PMEG2010BEV		
		550	0.07	low I_R										PMEG2010EA BAT760	PMEG2010AEJ	PMEG2010EV BAT960		
	30	620	1.5	low V_F													PMEG2010AEB	
		450	1.0	low V_F			1PS74SB23											
		360	1.5	low V_F	PMEG3010EP				PMEG3010ER									
		450	0.05	low I_R	PMEG3010BEP				PMEG3010BER									
		520	0.05	low I_R							PMEG3010CEH				PMEG3010CEJ			
		550	1	low V_F		PRLL5818												
		560	0.15	low V_F				PMEG3010ET			PMEG3010EH			PMEG3010BEA	PMEG3010EJ	PMEG3010BEV		
	40	680	0.5	low V_F													PMEG3010EB	
		490	0.05	low V_F	PMEG4010EP				PMEG4010ER									
		600	1.0	low V_F		PRLL5819												
		640	0.1	low V_F				PMEG4010ET			PMEG4010EH			PMEG4010BEA	PMEG4010EJ	PMEG4010BEV		
	60	570	0.05	low I_R							PMEG4010CEH				PMEG4010CEJ			
		530	0.06	low V_F	PMEG6010EP				PMEG6010ER									
		650	0.35	low V_F			PMEG6010AED											
	2.0	660	0.05	low I_R							PMEG6010CEH				PMEG6010CEJ			
		660	0.07	low I_R							PMEG2015EH			PMEG2015EA	PMEG2015EJ	PMEG2015EV		
1.5	20	550	1.0	low V_F							PMEG3015EH				PMEG3015EJ	PMEG3015EV		
	30	550	1.0	low V_F							PMEG1020EH			PMEG1020EA	PMEG1020EJ	PMEG1020EV		
2.0	10	460	3.0	low V_F										PMEG1020EH	PMEG1020EJ	PMEG1020EV		
		420	1.9	low V_F								PMEG2020EPA						
		525	0.2	low V_F							PMEG2020EH			PMEG2020AEA	PMEG2020EJ			
	30	360	3.0	low V_F	PMEG3020EP													
		420	1.5	low V_F	PMEG3020CEP				PMEG3020ER									
		450	0.1	low I_R	PMEG3020BEP													
		470	2.5	low V_F								PMEG3020EPA						
		520	0.05	low I_R	PMEG3020DEP				PMEG3020BER									
		620	1.0	low V_F							PMEG3020EH				PMEG3020EJ			
	40	490	0.1	low V_F	PMEG4020EP				PMEG4020ER									
		535	0.1	low V_F								PMEG4020EPA						
	60	530	0.15	low V_F	PMEG6020EP				PMEG6020ER									
		575	0.25	low V_F								PMEG6020EPA						
3.0	10	530	3.0	low V_F							PMEG1030EH				PMEG1030EJ			
	30	360	5.0	low V_F														

Medium power low V_F Schottky rectifiers dual ≥ 200 mA

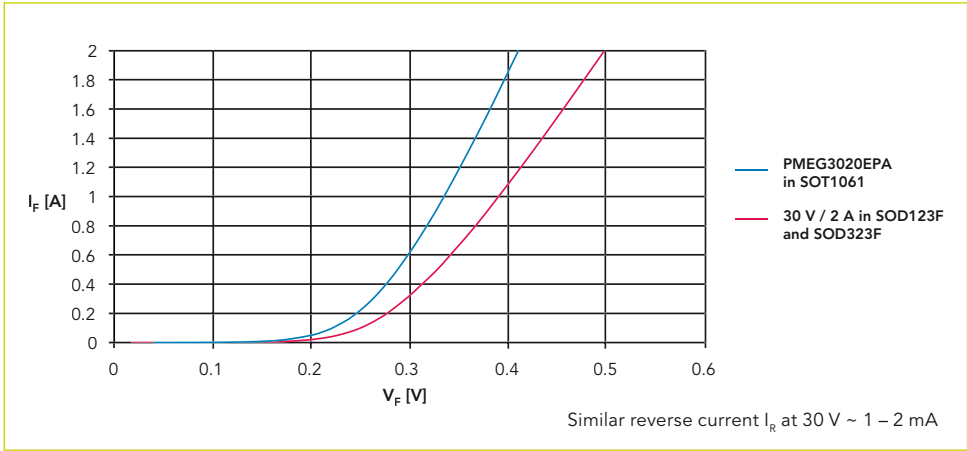
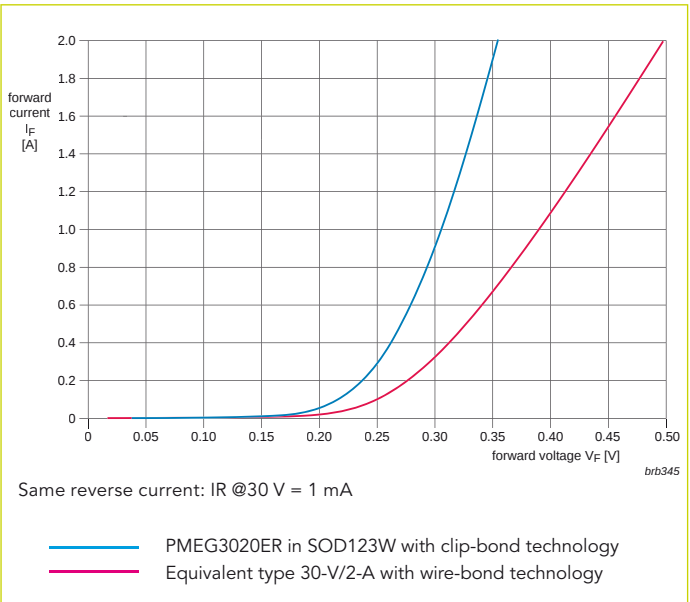
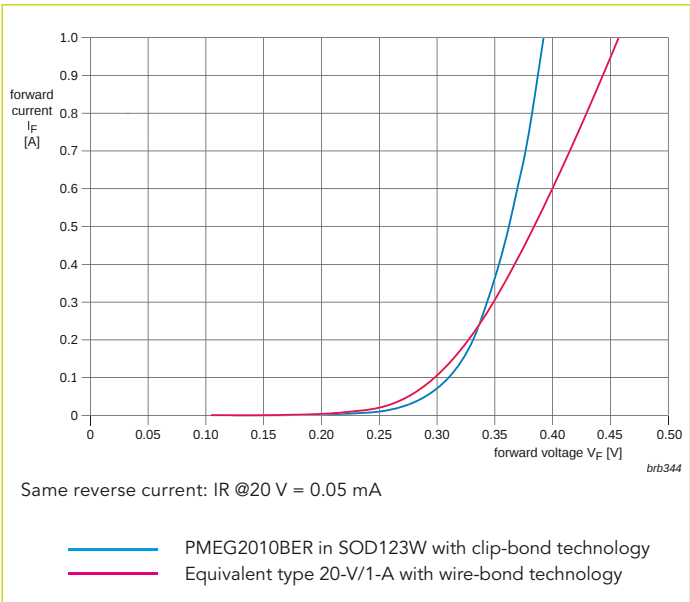
types in **bold** represent new products

Nomenclature of low V_F (MEGA) Schottky rectifiers



Improved forward characteristics of (MEGA) Schottky rectifiers in new packages

NXP low V_F maximum efficiency general applications (MEGA) Schottky rectifiers in new FlatPower SOD123W and medium power leadless SOT1061 package



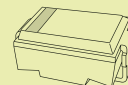
Low capacitance Schottky diodes

I _F max (mA)	V _R max (V)	V _F max (mV) @ I _F (mA)	C _d max (pF) @ V _R = 0 V	Package	SOT23	SOT323 (SC-70)	SOT363 (SC-88)	SOD323 (SC-76)	SOT666	SOD523 (SC-79)	SOD882
				Size (mm)							
				P _{tot} (mW)	250	250	300	400	300	500	250
30	4	450	1	 single BAT17							
				 single 1PS76SB17				1PS76SB17		1PS79SB17	
				 triple isolated					1PS66SB17		
				 dual series PMBD353 PMBD354 ¹⁾							
	15	340	1	 single		1PS70SB82					1PS10SB82
				 triple isolated			1PS88SB82		1PS66SB82		
				 dual series		1PS70SB84					
				 dual c.c.		1PS70SB85					
				 dual c.a.		1PS70SB86					

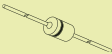
¹⁾ diodes have matched capacitance

PN rectifiers in SMA, SMB, SMC

types in **bold** represent new products

Package	SOD131 (SMA)				SOD132 (SMB)			SOD133 (SMC)			
											
	4.25 x 2.67 x 2.14				4.32 x 3.62 x 2.29			6.86 x 5.91 x 2.34			
Size (mm)		30				30			30		
t _r (ns)		30				30			30		
V _R max (V)	I _F max (A)										
50	1	ES1A	US1A	RS1A	S1A						
	1.5			RS2AA			RS2A	S2A			
	2					ES2A					
	3								ES3A	US3A	RS3A
100	1	ES1B	US1B	RS1B	S1B						
	1.5			RS2BA			RS2B	S2B			
	2					ES2B					
	3								ES3B	US3B	RS3B
200	1	ES1D	US1D	RS1D	S1D						
	1.5		US2DA	RS2DA	S2DA		RS2D	S2D			
	2					ES2D					
	3								ES3D	US3D	RS3D
400	1	ES1G	US1G	RS1G	S1G						
	1.5		US2GA	RS2GA	S2GA		RS2G	S2G			
	2					ES2G					
	3								ES3G	US3G	RS3G
600	1		US1J	RS1J	S1J		RS2J	S2J			
	1.5		US2JA	RS2JA	S2JA						
	3								US3J	RS3J	S3J
800	1		US1K	RS1K	S1K		RS2K	S2K			
	1.5			RS2KA	S2KA						
	3								US3K	RS3K	S3K
1000	1		US1M	RS1M	S1M		RS2M	S2M			
	1.5			RS2MA	S2MA						
	3								US3M	RS3M	S3M

General purpose switching diodes ≤ 100V

V_F max (V)	V_F max (V)	@ I_F (mA)	I_R max (mA)	@ V_R (V)	t_{rr} max (ns)	Package	SOD27 (DO-35)	SOD68 (DO-34)	SOD80C (MiniMelf)	SOT23		SOT143B	SOD123F	SOT323 (SC-70)	SOT363 (SC-88)	SOD323 (SC-76)	SOD323F (SC-90)	SOT666	SOT416 (SC-75)	SOD523 (SC-79)	SOD882	SOT883 (SC-101)
																						
							Size (mm) P _{tot} (mW)	4.25 x 1.85 x 0.56 500	3.04 x 1.6 x 0.55 500	3.5 x 1.5 x 1.5 500	2.9 x 1.3 x 1.0 250	2.9 x 1.3 x 1.0 250	2.6 x 1.6 x 1.1 830	2.0 x 1.25 x 0.95 200	2.0 x 1.25 x 0.95 300	1.7 x 1.25 x 0.95 400	1.7 x 1.25 x 0.7 550	1.6 x 1.2 x 0.55 180	1.6 x 0.8 x 0.77 170	1.2 x 0.8 x 0.6 500	1.0 x 0.6 x 0.5 250	1.0 x 0.6 x 0.5 250
50	1	50	100	50	4					BAL74												
70	1	50	1000	70	4					BAL99												
75	1	10	25	20	4			1N4531														
		50	1000	75	4						BAS28											
		100	5000	75	4				BAS32L													
90	1	50	500	80	4					BAW56				BAW56W					BAW56T			BAW56M
														BAW56S								
														BAV756S								
100	1	10	25	20	4		1N4148															
		50	500	80	4							BAS16H				BAS316	BAS16J					
										BAS16				BAS16W					BAS16T			
																				BAS516	BAS16L	
															BAS16VY			BAS16VV				
										BAV70				BAV70W					BAV70T			BAV70M
															BAV70S							
										BAV99				BAV99W								
															BAV99S							

General purpose switching diodes > 100V

types in **bold** represent new products

V_R max (V)	V_F max (V)	@ I_F (mA)	I_R max (nA)	@ V_R (V)	t_{rr} max (ns)	Package	SOD27 (DO-35)	SOD80C (MiniMelf)	SOT457 (SC-74)	SOT23	SOT143B	SOD123F	SOT323 (SC-70)	SOT363 (SC-88)	SOD323 (SC-76)	SOD323F (SC-90)	SOD523 (SC-79)
						Size (mm)											
						P _{tot} (mW)	500	300	500	250	250	830	350	300	400	550	500
																	
150	1	100	100	150	50		BAV20										
≥ 200	1	100	100	200	150		BAV21	BAV103				BAS21H			BAS321		
					50					BAS21			BAS21W				
											BAV23						
										BAV23A			BAS21AW				
										BAV23C							
										BAV23S			BAS21SW				
									BAS21VD								
																BAS21J	BAS521
										BAS101							
										BAS101S							
											BAW101						
300	1.1	100	150	250	50												BAS101S

Controlled avalanche switching diodes

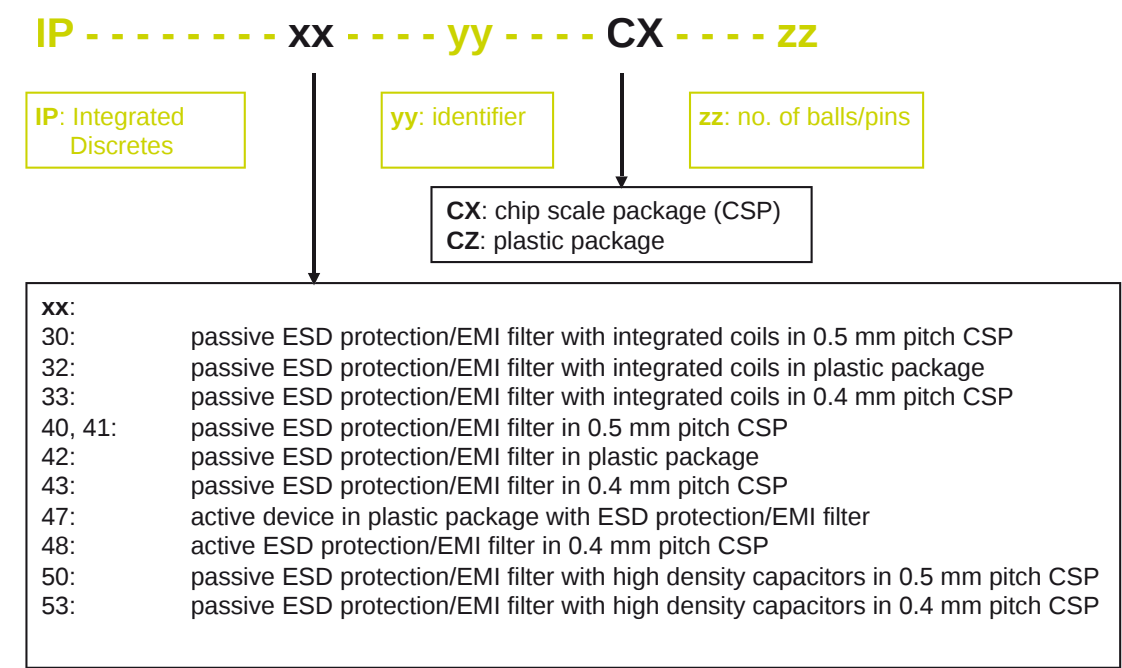
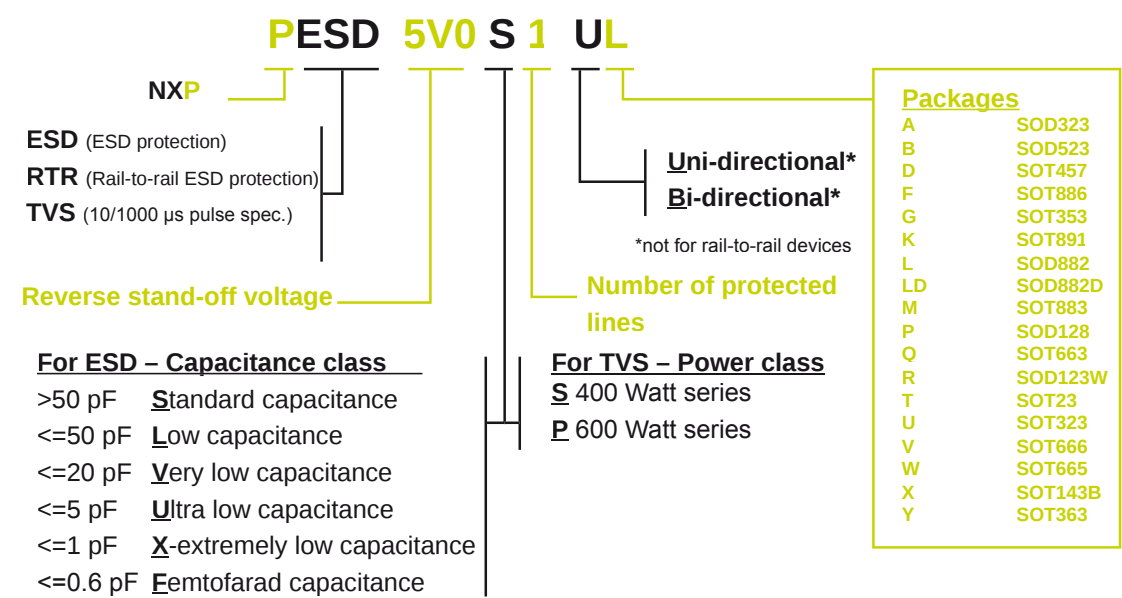
V_R max (V)	V_F max (V)	@ I_F (mA)	I_{gR} max (nA) @ V_R max	I_{FSM} max (A)	I_{PRM} max (mA)	C_j max (pF)	t_{rr} max (ns)	Package	SOT23	SOT143B
								Size (mm)		
								P _{tot} (mW)	250	250
										
60	1	200	100	9	600	2.5	6			BAS56
90	1	200	100	10	600	35	50		BAS29	
									BAS31	
									BAS35	

Low leakage current switching diodes

types in **bold** represent new products

V_R max (V)	V_F max (V)	@ I_F (mA)	I_R max (nA) @ V_R max	t_{rr} max (ns)	Package	SOD80C (MiniMelf)	SOD68 (DO-34)	SOT23	SOD123F	SOT323 (SC-70)	SOD323 (SC-76)	SOT416 (SC-75)	SOD523 (SC-79)
					Size (mm)								
					P _{tot} (mW)	300	500	250	830	250	400	170	500
													
75	1	10	5	3					BAS116H		BAS416		BAS716
								BAS116				BAS116T	
								BAV199		BAV199W			
								BAW156					
								BAV170					
													
125	1	100	1	1.5 typ		BAS45AL	BAS45A						

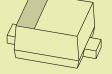
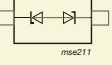
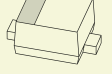
Protection and signal conditioning nomenclature



Protection and signal conditioning

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TVS diodes, 600 W	45

Low capacitance ESD protection devices

Number of protected lines		V _{RWM} (V)	C _{line} typ (pF)	C _{line} max (pF)	P _{PP} ^[1] max (W)	ESD rating ^[2] max (kV)	I _R max (μA) @ V _{RWM}	Configuration	Type	Package	Size (mm)
Unidirectional	Bidirectional										
1	0	3.3	34	40	45	30	0.3		PESD3V3L1UL		1.0 x 0.6 x 0.5
		5	25	30	42	26	0.1		PESD5V0L1UL		
		3.3	34	40	45	30	0.3		PESD3V3L1UB		1.2 x 0.8 x 0.6
		5	25	30	42	26	0.1		PESD5V0L1UB		
		3.3	34	40	45	30	0.3		PESD3V3L1UA		1.7 x 1.25 x 0.95
		5	25	30	42	26	0.1		PESD5V0L1UA		
		3.3	2.6	3.1	-	9	0.1 (@ 3 V)		PESD3V3U1UL		1.0 x 0.6 x 0.5
		5	2	2.6	-	9	0.1		PESD5V0U1UL		
		3.3	2.6	3.1	-	9	0.1 (@ 3 V)		PESD3V3U1UB		1.2 x 0.8 x 0.6
		5	2	2.6	-	9	0.1		PESD5V0U1UB		
		3.3	2.6	3.1	-	9	0.1 (@ 3 V)		PESD3V3U1UA		1.7 x 1.25 x 0.95
		5	2	2.6	-	9	0.1		PESD5V0U1UA		
0	1	3.3	101	-	500	30	2		PESD3V3L1BA		1.7 x 1.25 x 0.95
		5	75	-	500	30	1		PESD5V0L1BA		
		12	19	-	200	30	0.05		PESD12VL1BA		
		15	16	-	200	30	0.05		PESD15VL1BA		
		24	11	-	200	23	0.05		PESD24VL1BA		
		5	11	13	45	30	0.01		PESD5V0V1BL		1.0 x 0.6 x 0.5
		5	11	13	45	30	0.01		PESD5V0V1BB		1.2 x 0.8 x 0.6
		5	11	13	45	30	0.01		PESD5V0V1BA		1.7 x 1.25 x 0.95
		5	2.9	3.5	-	10	0.1		PESD5V0U1BL		1.0 x 0.6 x 0.5
		5	2.9	3.5	-	10	0.1		PESD5V0U1BB		1.2 x 0.8 x 0.6
		5	2.9	3.5	-	10	0.1		PESD5V0U1BA		1.7 x 1.25 x 0.95

^[1] 8/20 μs surge pulse acc. to IEC 61000-4-5 ^[2] acc. to IEC 61000-4-2 (contact discharge)

Low capacitance ESD protection devices

Low capacitance ESD protection devices

types in **bold** represent new products

Number of protected lines		V_{RWM} (V)	C_{line} typ (pF)	C_{line} max (pF)	$P_{PP}^{[1]}$ max (W)	ESD rating ^[2] max (kV)	I_R max (μA) @ V_{RWM}	Configuration	Type	Package	Size (mm)
Unidirectional	Bidirectional										
0	4	5	2.9	3.5	-	10	0.1		PESD5V0U4BF	SOT886 (XSON6)	1.45 x 1.0 x 0.5
		5	2.9	3.5	-	10	0.1		PESD5V0U4BW	SOT665	1.6 x 1.2 x 0.55
5	4	3.3	22		25	20	1		PESD3V3L5UK	SOT891 (XSON6)	1.0 x 1.0 x 0.5
		5	16		25	20	0.025		PESD5V0L5UK		
		3.3	22	28	25	20	0.3		PESD3V3L5UF	SOT886 (XSON6)	1.45 x 1.0 x 0.5
		5	16	19	25	20	0.025		PESD5V0L5UF		
		3.3	22	28	25	20	0.3		PESD3V3L5UV	SOT666	1.6 x 1.2 x 0.55
		5	16	19	25	20	0.025		PESD5V0L5UV		
		3.3	22	28	25	20	0.3		PESD3V3L5UY	SOT363 (SC-88)	2.0 x 1.25 x 0.95
		5	16	19	25	20	0.025		PESD5V0L5UY		
0	5	5	2.9	3.5	-	10	0.1		PESD5V0U5BF	SOT886 (XSON6)	1.45 x 1.0 x 0.5
		5	2.9	3.5	-	10	0.1		PESD5V0U5BV	SOT666	1.6 x 1.2 x 0.55
6	5	5	16	19	35	20	0.025		PESD5V0L6UAS	SOT505 (TSSOP8)	3.0 x 3.0 x 1.1
		5	16	19	35	20	0.025		PESD5V0L6US	SOT96 (SO8)	4.9 x 3.9 x 1.75
0	7	5	8	10	35	10	0.025		PESD5V0L7BAS	SOT505 (TSSOP8)	3.0 x 3.0 x 1.1
		5	8	10	35	10	0.025		PESD5V0L7BS	SOT96 (SO8)	4.9 x 3.9 x 1.75

^[1] 8/20 μs surge pulse acc. to IEC 61000-4-5 ^[2] acc. to IEC 61000-4-2 (contact discharge)

ESD protection for very high speed interfaces (< 2 pF)

types in **bold** represent new products

Number of protected lines		V_{RWM} (V)	C_{line} typ (pF)	C_{line} max (pF)	ESD rating ^[2] max (kV)	I_R max (μA) @ V_{RWM}	Configuration	Type	Package	Size (mm)
Unidirectional	Bidirectional									
1	0	5	0.9	1	8	0.2		PESD5V0X1UB	SOD523 (SC-79)	1.2 x 0.8 x 0.6
		5	1.8	2	15	0.2		PESD5V0X1UAB		
		16	0.83	0.95	8	0.1		PESD16VX1UL	SOD882	1.0 x 0.6 x 0.5

ESD protection for very high speed interfaces (< 2 pF)

ESD protection for very high speed interfaces (< 2 pF)

types in **bold** represent new products

Number of protected lines		V _{RWM} (V)	C _{line} typ (pF)	C _{line} max (pF)	ESD rating ^[1] max (kV)	I _R max (μA) @ V _{RWM}	Configuration	Type	Package	Size (mm)
Unidirectional	Bidirectional									
2	0	5.5	0.7	-	8	-		IP4282CZ6	SOT886 (XSON6)	1.45 x 1.0 x 0.5
		5.5	1.3	-	15	-		IP4359CX4	CSP	0.76 x 0.76 x 0.61
4	0	5.5	1	-	8	-		IP4220CZ6	SOT457 (SC-74)	2.9 x 1.5 x 1.0
		5.5	1	-	8	-		IP4221CZ6-S	SOT886 (XSON6)	1.45 x 1.0 x 0.5
		5.5	1	-	8	-		IP4221CZ6-XS	SOT891 (XSON6)	1.0 x 1.0 x 0.5
		5.5	1	-	8	-		IP4233CZ6	SOT363 (SC-88)	2.0 x 1.25 x 0.95
		5.5	1	-	8	-		PRTR5V0U4AD	SOT457 (SC-74)	2.9 x 1.5 x 1.0
		5.5	1	-	8	-		PRTR5V0U4D		
		5.5	1	-	8	-		PRTR5V0U4Y	SOT363 (SC-88)	2.0 x 1.25 x 0.95
		5.5	0.7	-	8	-		IP4280CZ10	SOT552 (TSSOP10)	3.0 x 3.0 x 1.1
		5.5	0.7	-	8	-		IP4281CZ10	SOT1059 (XSON10U)	1.0 x 2.5 x 0.5
		5.5	0.6	-	8	-		IP4283CZ10-TB		
		5.5	0.6	-	8	-		IP4283CZ10-TT	SOT552 (TSSOP10)	3.0 x 3.0 x 1.1
		5.5	1	-	8	-				
		5.5	1	-	8	-				
		5.5	1	-	8	-				
		5.5	1	-	8	-				
		5.5	1	-	8	-				

^[1] 8/20 μs surge pulse acc. to IEC 61000-4-5

ESD protection for very high speed interfaces (< 2 pF)

ESD protection for very high speed interfaces (< 2 pF)

types in **bold** represent new products

Number of protected lines		V _{RWM} (V)	C _{line} typ (pF)	C _{line} max (pF)	ESD rating ^[1] max (kV)	I _R max (μA) @ V _{RWM}	Configuration	Type	Package	Size (mm)
Unidirectional	Bidirectional									
4	0	5.5	0.6	-	8	-		IP4286CZ6-TBF	SOT886 (XSON6)	1.45 x 1.0 x 0.5
		5.5	0.6	-	8	-		IP4286CZ6-TTY	SOT363 (SC-88)	2.0 x 1.25 x 0.95
		5.5	0.5	-	8	-		IP4284CZ10-TB	SOT1059 (XSON10U)	1 x 2.5 x 0.5
		5.5	0.5	-						

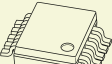
Audio interfaces

types in **bold** represent new products

Baseband interface	Number of protected lines	Line small-signal equivalents		Digital interface clock speed (MHz)	Remark	Type	Package	Size (mm)
		R_{line}	C_{line} (pF)					
Audio	2	0.9 Ω	290	-	Low-ohmic speaker (< ~8 Ω)	IP4047CX6/LF	6 ball CSP	1.56 x 1.01 x 0.65
		10 Ω	200	-	Low-ohmic speaker (> ~8 Ω)	IP4048CX5/LF	0.91 x 1.28 x 0.65	0.91 x 1.28 x 0.65
		15 Ω	5000	-	Low-ohmic speaker (> ~8 Ω)	IP5311CX5/LF	5 ball CSP	0.80 x 1.16 x 0.61
		68 Ω	110	-	Single-ended or differential microphone	IP4049CX5/LF	0.91 x 1.28 x 0.65	
		470 Ω	35	-	Single-ended or differential microphone	IP4055CX6/LF	6 ball CSP	1.56 x 1.03 x 0.65
		470 Ω	20	-	Single-ended or differential microphone	IP4355CX6/LF		1.16 x 0.76 x 0.65
		50 Ω / 2.2 k Ω	2000	-	Single-ended to quasi-differential microphone channel with integrated biasing network	IP5002CX8/LF	8 ball CSP	1.67 x 1.67 x 0.65
		2.25 k Ω	4000	-	Differential microphone filter with integrated biasing network for $\Sigma\Delta$ ADC converters	IP5006CX11/LF	11 ball CSP	1.41 x 1.91 x 0.65
		5 Ω / 20 Ω / 1.5 k Ω	550	-	Differential microphone filter with integrated biasing network for $\Sigma\Delta$ including coupling capacitors	IP5020CX16/LF	16 ball CSP	2.01 x 1.91 x 0.65
		0.25 Ω , 3 nH	-	-	Inductive, low-ohmic differential channel LC filter	IP3047CX6	6 ball CSP	1.60 x 1.15 x 0.65
		0.25 Ω , 3 nH	-	-	Inductive, low-ohmic differential channel LC filter	IP3048CX5	5 ball CSP	1.51 x 1.15 x 0.65
		2.2 k Ω / 1 k Ω / 0.8 k Ω	0.8 nF / 1.6 nF	-	Differential microphone biasing ESD protection / EMI filtering	IP5306CX8	8 ball CSP	1.19 x 1.19 x 0.61
	4	10 Ω	5000	-	Dual differential speaker	IP5040CX11/LF	11 ball CSP	1.41 x 2.01 x 0.65
	6	15 Ω / 95 Ω	65 / 33	-	Single-ended microphone and high-ohmic speaker (> ~8 Ω) with integrated 2 kohm pull-up resistor	IP4363CX10/LF	10 ball CSP	0.76 x 1.96 x 0.61
		40 Ω / 1450 Ω / 10 Ω	50 / 20 / 200	-	Fully integrated audio interface protection for differential microphone and differential speaker, including EMI filtering and pull up resistors	IP4025CX20/LF	20 ball CSP	1.98 x 2.53 x 0.65
		40 Ω / 1450 Ω / 10 Ω	50 / 20 / 200	-	Fully integrated audio interface protection for differential microphone and differential speaker, including EMI filtering and pull up resistors	IP4027CX20/LF		1.91 x 2.52 x 0.65
		50 Ω / 10 Ω	50 / 100 / 1000	-	Fully integrated audio interface protection for differential microphone and differential speaker, including EMI filtering and pull up resistors	IP4125CX20/LF		2.00 x 2.66 x 0.65
	8	0.8 Ω / 30 Ω / 200 Ω	20 / 50 / 150	~20	Fully integrated audio interface protection including EMI filtering for microphone and speaker, and additional 4-channel EMI filter	IP4110CX20/LF		1.91 x 2.47 x 0.65

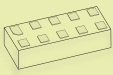
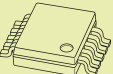
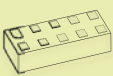
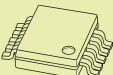
Video interfaces

types in **bold** represent new products

Baseband interface	Number of protected lines	Buffer	Level shifter	C_{line} (pF)	Resistor (Ω)	Remark	Type	Package	Size (mm)
Display port	4	-	-	0.6	-	ESD protection for ultra high speed interfaces	IP4283CZ10-TB	SOT1059 (XSON10U) 	1.0 x 2.5 x 0.5
		-	-	0.6	-	ESD protection for ultra high speed interfaces	IP4283CZ10-TT	SOT552 (TSSOP10) 	3.0 x 3.0 x 1.1
		-	-	0.5	-	ESD protection for ultra high speed interfaces	IP4284CZ10-TB	SOT1059 (XSON10U) 	1.0 x 2.5 x 0.5
		-	-	0.5	-	ESD protection for ultra high speed interfaces	IP4284CZ10-TT	SOT552 (TSSOP10) 	3.0 x 3.0 x 1.1
		-	-	0.6	-	ESD protection for ultra high speed interfaces	IP4286CZ6-TBF	SOT886 (XSON6) 	1.45 x 1.0 x 0.5
						ESD protection			

Video interfaces

types in **bold** represent new products

Baseband interface	Number of protected lines	Buffer	Level shifter	C _{line} (pF)	Resistor (Ω)	Remark	Type	Package	Size (mm)
HDMI	4	-	-	0.6	-	ESD protection for ultra high speed interfaces	IP4283CZ10-TB		1.0 x 2.5 x 0.5
		-	-	0.6	-	ESD protection for ultra high speed interfaces	IP4283CZ10-TT		3.0 x 3.0 x 1.1
		-	-	0.6	-	ESD protection for ultra high speed interfaces	IP4286CZ6-TBF		1.45 x 1.0 x 0.5
							IP4286CZ6-TTY		2.0 x 1.25 x 0.95
		-	-	0.5	-	ESD protection for ultra high speed interfaces	IP4284CZ10-TB		1.0 x 2.5 x 0.5
		-	-	0.5	-	ESD protection for ultra high speed interfaces	IP4284CZ10-TT		3.0 x 3.0 x 1.1
	5	-	-	0.5	-	ESD protection for up to 5 ultra high speed datalines	PESD5V0F5BK		1.0 x 1.0 x 0.5
		-	-	10	1.75 k, 100 k	HDMI, DDC, CEC, hotplug ESD protection and biasing	IP4310CX8	8 ball CSP	1.16 x 1.16 x 0.61
	8	-	-	1.3	-	HDMI, TMDS line ESD protection	IP4309CX9	9 ball CSP	1.16 x 1.16 x 0.61
	12	-	yes	0.7	-	ESD protection and level shifting for a complete HDMI port	IP4776CZ38		9.7 x 4.4 x 1.1
		yes	yes	0.7	-	ESD protection, DDC buffering, noise reduction and Hot Plug application for a complete HDMI source port	IP4777CZ38		
		yes	yes	0.7	-	ESD protection, DDC buffering, noise reduction and Hot Plug application for a complete HDMI sink port	IP4778CZ38		

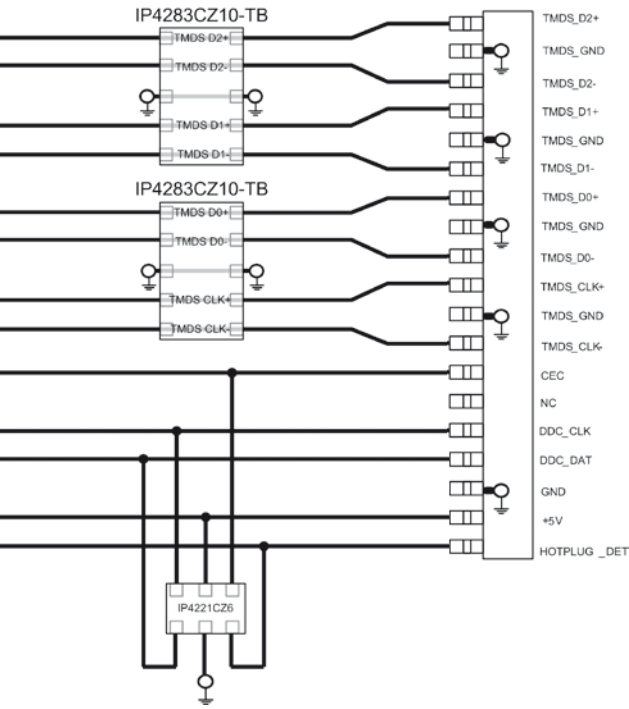
Video interfaces

types in **bold** represent new products

Baseband interface	Number of protected lines	Buffer	Level shifter	C _{line} (pF)	Resistor (Ω)	Remark	Type	Package	Size (mm)
VGA	7	yes	yes	5	55	H&V sync buffer, DDC level shifter	IP4770CZ16		4.9 x 3.9 x 1.73
		yes	yes	5	65	H&V sync buffer, DDC level shifter	IP4771CZ16		4.9 x 3.9 x 1.73
		yes	yes	5	10	H&V sync buffer, DDC level shifter	IP4772CZ16		4.9 x 3.9 x 1.73
		yes	no	4	10	VGA receivers and transmitters, H&V sync buffer	IP4773CZ14		6.2 x 5.3 x 2.0
		yes	no	4	10	VGA receivers and transmitters, H sync buffer	IP4774CZ14		6.2 x 5.3 x 2.0
		no	yes	4	1.3 - 2.4	VGA receivers and transmitters, DDC level shifter	IP4769CZ14		5.0 x 4.4 x 1.1

For ultra high speed single line ESD protection please refer to pages 29 - 31

HDMI ESD protection using IP4283CZ10-TB and IP4221CZ6-S



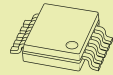
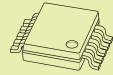
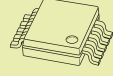
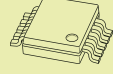
USB, LVDS, SATA, LAN

types in **bold** represent new products

Baseband interface	Number of protected lines	R_{line}	C_{line} (pF)	Digital interface clock speed (MHz)	Remark	Type	Package	Size (mm)
USB2.0 (Plastic package)	2	-	1	-	ESD protection for up to 2 ultra high speed datalines	PRTR5V0U2K		1.0 x 1.0 x 0.5
		-	1	-	ESD protection for up to 2 ultra high speed datalines	PRTR5V0U2D		2.9 x 1.5 x 1.0
		-	1	-	ESD protection for up to 2 ultra high speed datalines	PRTR5V0U2F		1.45 x 1.0 x 0.5
	4	-	1	-	ESD protection for USB2.0 high- speed, SD-Card, SIM card	IP4221CZ6-S		2.9 x 1.5 x 1.0
		-	1	-	ESD protection for USB2.0 high- speed, SD-Card, SIM card	IP4220CZ6		
		-	1	-	Dual USB2.0, ESD protection	IP4220CZ6		
		-	1	-	ESD protection, as IP4220CZ6 but different bonding	PRTR5V0U4AD		
		-	1	-	ESD protection, as IP4220CZ6 but different package	PRTR5V0U4Y		2.0 x 1.25 x 0.95
		-	1	-	ESD protection for USB2.0 high-speed, SD-Card, SIM card	IP4221CZ6-S		1.45 x 1.0 x 0.5
		-	1	-	ESD protection for USB2.0 high-speed, SD-Card, SIM card	IP4221CZ6-XS		1.0 x 1.0 x 0.5
		1	3	-	>15 kV IEC contact ESD protection with pi-filter	IP4225CZ10		2.9 x 1.5 x 1.0

USB, LVDS, SATA, LAN

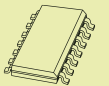
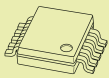
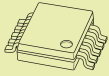
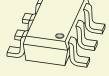
types in **bold** represent new products

Baseband interface	Number of protected lines	R_{line}	C_{line} (pF)	Digital interface clock speed (MHz)	Remark	Type	Package	Size (mm)
USB3.0 SuperSpeed USB / USB2.0	4	-	0.6	-	ESD protection for ultra high speed interfaces	IP4283CZ10-TB		1.0 x 2.5 x 0.5
		-	0.6	-	ESD protection for ultra high speed interfaces	IP4283CZ10-TT		3.0 x 3.0 x 1.1
		-	0.5	-	ESD protection for ultra high speed interfaces	IP4284CZ10-TB		1.0 x 2.5 x 0.5
		-	0.5	-	ESD protection for ultra high speed interfaces	IP4284CZ10-TT		3.0 x 3.0 x 1.1
	5	-	0.5	-	ESD protection for up to 5 ultra high speed datalines	PESD5V0F5BK		1.0 x 1.0 x 0.5
Display port	4	0.6	0.6	-	ESD protection for ultra high speed interfaces	IP4283CZ10-TB		1.0 x 2.5 x 0.5
		-	0.6	-	ESD protection for ultra high speed interfaces	IP4283CZ10-TT		3.0 x 3.0 x 1.1
		-	0.5	-	ESD protection for ultra high speed interfaces	IP4284CZ10-TB		1.0 x 2.5 x 0.5
		-	0.5	-	ESD protection for ultra high speed interfaces	IP4284CZ10-TT		3.0 x 3.0 x 1.1
		-	0.6	-	ESD protection for high speed interfaces	IP4286CZ6-TBF		1.45 x 1.0 x 0.5

Protection and signal conditioning

USB, LVDS, SATA, LAN

types in **bold** represent new products

Baseband interface	Number of protected lines	R_{line}	C_{line} (pF)	Digital interface clock speed (MHz)	Remark	Type	Package	Size (mm)
Display port	4	-	0.6	-	ESD protection for ultra high speed interfaces	IP4286CZ6-TTY	SOT363 (SC-88) 	2.0 x 1.25 x 0.95
	11	-	0.7	-	ESD protection	IP4790CZ38	SOT510 (TSSOP38) 	9.7 x 4.4 x 1.1
LVDS	10	-	5	-	100 Ω termination	IP4263CZ14	SOT108 (SO14) 	8.65 x 3.9 x 1.75
SATA	2	-	0.7	-	ESD protection for ultra high speed interfaces	IP4282CZ6	SOT886 (XSON6) 	1.45 x 1.0 x 0.5
		-	0.6	-	ESD protection for ultra high speed interfaces	IP4286CZ6-TBF		
		-	0.6	-	ESD protection for ultra high speed interfaces	IP4286CZ6-TTY	SOT363 (SC-88) 	2.0 x 1.25 x 0.95
	4	-	0.6	-	ESD protection for ultra high speed interfaces	IP4283CZ10-TB	SOT1059 (XSON10U) 	1.0 x 2.5 x 0.5
		-	0.6	-	ESD protection for ultra high speed interfaces	IP4283CZ10-TT	SOT552 (TSSOP10) 	3.0 x 3.0 x 1.1
		-	0.5	-	ESD protection for ultra high speed interfaces	IP4284CZ10-TB	SOT1059 (XSON10U) 	1.0 x 2.5 x 0.5
		-	0.5	-	ESD protection for ultra high speed interfaces	IP4284CZ10-TT	SOT552 (TSSOP10) 	3.0 x 3.0 x 1.1
	4	55	5	-	ESD protection and termination for IEEE1394	IP4224CZ6	SOT457 (SC-74) 	2.9 x 1.5 x 1.0

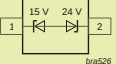
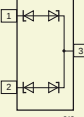
USB, LVDS, SATA, LAN

types in **bold** represent new products

Baseband interface	Number of protected lines	R_{line}	C_{line} (pF)	Digital interface clock speed (MHz)	Remark	Type	Package	Size (mm)
LAN	1	-	0.6	-	Ethernet ESD protection $V_{RWM}=3.3$ V	PESD3V3U1UT		2.9 x 1.3 x 1.0
		-	0.6	-	Ethernet ESD protection $V_{RWM}=5.0$ V	PESD5V0U1UT		
		-	0.6	-	Ethernet ESD protection $V_{RWM}=12$ V	PESD12VU1UT		
		-	0.6	-	Ethernet ESD protection $V_{RWM}=15$ V	PESD15VU1UT		
		-	0.6	-	Ethernet ESD protection $V_{RWM}=24$ V	PESD24VU1UT		
	4	-	1	-	Ethernet ESD protection	IP4220CZ6	SOT457 (SC-74) 	2.9 x 1.5 x 1.0
		-	1	-	Ethernet line surge ESD protection	IP4233CZ6	SOT363 (SC-88) 	2.0 x 1.25 x 0.95

For ultra high speed single line ESD protection please refer to pages 29 - 31

Automotive LIN/CAN/FlexRay

Number of protected lines bidirectional	V_{RWM} (V)	C_{line} typ (pF)	C_{line} max (pF)	$P_{PP}^{(1)}$ max (W)	ESD rating ^[2] max (kV)	I_T max [μA] @ V_{RWM}	Configuration	Type	Package	Size (mm)
1	15 (diode 1) 24 (diode 2)	13	17	160	23	0.05		PESD1LIN	SOD323 (SC-76) 	1.7 x 1.25 x 0.95
2	24	11	17	200	23	0.05		PESD1CAN		2.9 x 1.3 x 1.0
		25	30	230	30	0.01		PESD2CAN		2.9 x 1.3 x 1.0
		11	17	200	23	0.05		PESD1FLEX		2.9 x 1.3 x 1.0

^[1] 8/20 <



Small-signal transistors

General purpose bipolar transistors

48

Single transistors	48
Double transistors	49
Single and double switching transistors	49
Matched pair transistors	50
High voltage transistors	51
Low noise transistors	51
Darlington transistors	51
Medium frequency transistors	52
Schmitt trigger	52
MOSFET driver	53

Resistor-equipped transistors (RETs)

54

RETs 100 mA single	54
RETs 100 mA double	55
RETs 500 mA	55
Low V_{CEsat} (BISS) RETs	55

Low V_{CEsat} (BISS) transistors

56

Low V_{CEsat} (BISS) transistors single NPN	56
Low V_{CEsat} (BISS) transistors single PNP	58
Low V_{CEsat} (BISS) transistors double	60
Low V_{CEsat} (BISS) load switches	61
High voltage low V_{CEsat} (BISS) transistors	62
Low V_{CEsat} modules - Schottky diode / (BISS) transistor	62
Low V_{CEsat} (BISS) RETs	63
Advantages of low V_{CEsat} (BISS) technology	63

Medium power transistors

64

Medium power low V_{CEsat} (BISS) transistors NPN	64
Medium power low V_{CEsat} (BISS) transistors PNP	65
Medium power general purpose transistors	65

Medium frequency transistors

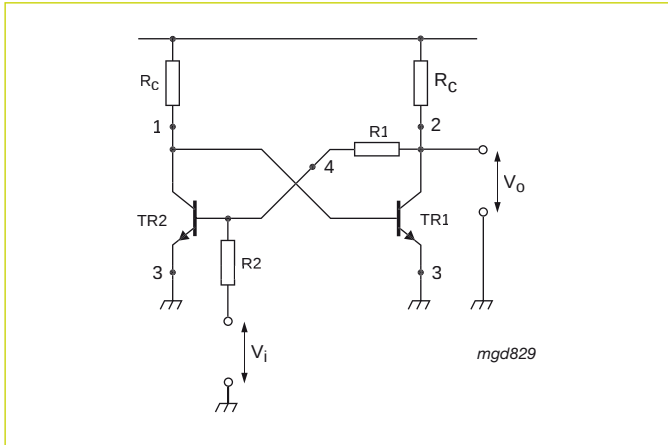
Package						SOT23	SOT323 (SC-70)
							
Size (mm)						2.9 x 1.3 x 1.0	2.0 x 1.25 x 0.95
P _{tot} (mW)						250	200
Polarity	V _{CEO} (V)	I _C (mA)	h _{FE} min	h _{FE} max	f _T typ (MHz)		
NPN	15	100	40	-	500	BF570	
	20	25	40	85	> 275	BFS20	BFS20W
		30	65	225	260	BFS19	
PNP	40	25	67	220	380	BF840	
	30	25	25	50	250	BF824	BF824W
	40	25	50	-	> 325	BF550	

Schmitt trigger

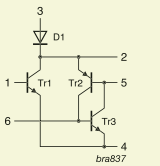
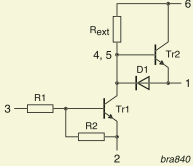
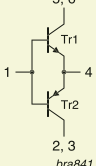
Package							SOT143B
							
Size (mm)							2.9 x 1.3 x 1.0
P _{tot} (mW)							250
Polarity	V _{CEO} (V) TR1	V _{CEO} (V) TR2	I _C (mA)	h _{FE} min	h _{FE} max	V _{CEsat} typ (mV)	
NPN	30	6	100	110	800	250	BCV63 / B
PNP	30	6	100	220	475	250	BCV64B

- Key features
- ▶ Low current (max. 100 mA)
 - ▶ Low voltage (max. 30 and 6 V)
- Key benefits
- ▶ Reduced component count and pick-and-place costs
 - ▶ Smaller designs
- Key applications
- ▶ General purpose switching and amplification
 - ▶ Schmitt trigger applications

Schmitt trigger

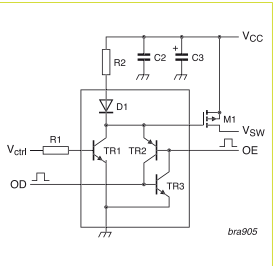


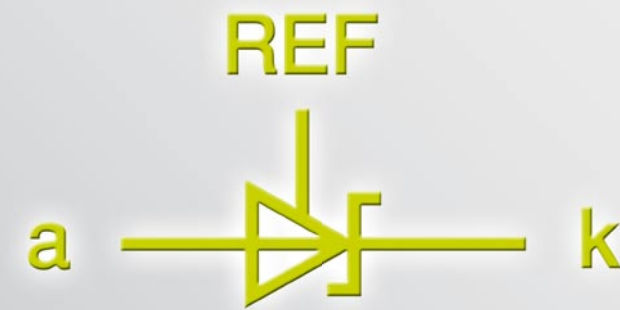
MOSFET driver

Package						SOT457 (SC-74)		
								
Size (mm)						2.9 x 1.5 x 1.0		
P _{tot} (mW)						400	400	580
Configuration								
Contains		I _C (A)	I _{CM} (A)			R1 = R2 (kΩ)		
				PMD9050D		-	PMD9010D	BCV65 (SOT143B)
General purpose transistors		0.1	0.2			2.2	PMD9001D	
						4.7	PMD9002D	
						10	PMD9003D	
Switching transistors - reduced storage time		0.6	1.0			-		PMD2001D
Low V _{CEsat} (BISS) transistors - Low V _{CEsat} , high h _{FE} and I _C		1.0	2.0			-		PMD3001D

- Key features
- ▶ Three different configurations
 - ▶ Types available with standard, switching and low V_{CEsat} (BISS) transistors
 - ▶ Small footprint packages
- Key benefits
- ▶ Reduced component count
 - ▶ Smaller end products
- Key applications
- ▶ MOSFET driver
 - ▶ Bipolar power transistor driver
 - ▶ Push-pull driver

MOSFET driver with hardware output disable function





Standard linear products

Adjustable shunt voltage regulator IC	68
Low-dropout adjustable and fixed linear voltage regulator	69
Discrete voltage regulator	69
Constant current source	70

Constant current source

Constant current source

SOT353 (SC-88A)							
Package							
Size (mm)	2.0 x 1.25 x 0.95						
P _{tot} (mW)	335						
Type	PSSI2021SAY						
Description	maximum supply voltage	maximum supply current	typical stabilized output current	minimum stabilized output current	maximum stabilized output current	typical load stability of stabilized output current	typical output current change over ambient temperature
Parameter	V _S max (V)	I _S max (mA)	I _{out} typ (µA)	I _{out} min (mA)	I _{out} max (mA)	ΔI _{out} /I _{out} typ (%)	ΔI _{out} /I _{out} typ (°C)
Condition		@ V _S = 12 V; I _{out} = 15 µA; V _{out} = 1 V to 10 V	@ V _S = 12 V; V _{out} = 1 V to 10 V; R _{ext} = open			@ V _S = 12 V; V _{out} = 1 V to 10 V	@ V _S = 12 V; V _{out} = 1 V; T _{amb} = -55 °C to 150 °C
Value	75>	2.2	15	0.015	50	0.5	0.15

Key features

- ▶ Single-chip constant current source
- ▶ Output current set by an external resistor
- ▶ Very small footprint package

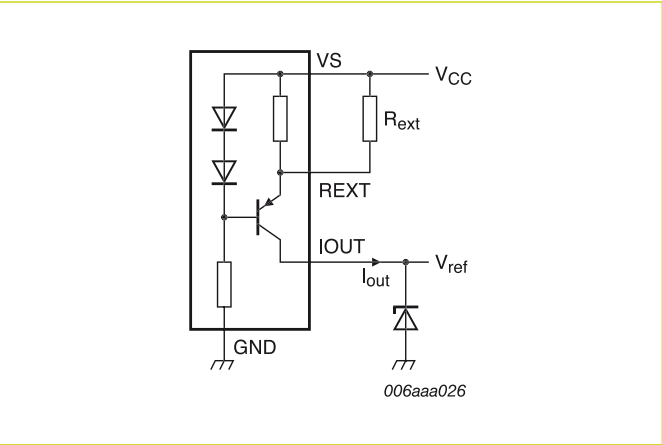
Key benefits

- ▶ Reduced component count and pick-and-place costs
- ▶ Smaller designs

Key applications

- ▶ Constant current LED driver
- ▶ Generic constant current source
- ▶ Active bias control for audio amplifiers

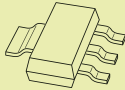
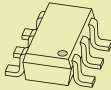
Voltage reference



MOSFETs

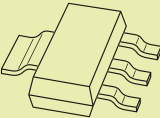
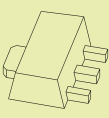
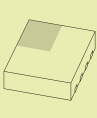
Small-signal MOSFETs	72
Small-signal MOSFETs single (N-channel) < 50 V	72
Small-signal MOSFETs single (N-channel) ≥ 50 V	74
Small-signal MOSFETs dual (N-channel)	76
Small-signal MOSFETs single (P-Channel)	76
Small-signal MOSFET dual (P-channel) and FET-KYs	76
Power MOSFETs	78
Power MOSFETs single (N-channel)	78
Power MOSFETs single (P-channel)	84
Power MOSFETs dual (N- and P-channel)	85

Small-signal MOSFETs single (N-channel) < 50V

Package													SOT223 (SC-73)		TSOP6 SOT457 (SC-74)	SOT23	SOT363 (SC-88)	SOT323 (SC-70)	SOT416 (SC-75)	SOT883 (SC-101)
																				
Size (mm)													6.5 x 3.5 x 1.65		2.9 x 1.5 x 1.0	2.9 x 1.3 x 1.0	2.0 x 1.25 x 0.95	2.0 x 1.25 x 0.95	1.6 x 0.8 x 0.77	1.0 x 0.6 x 0.5
P _{tot} (mW)													1700		600	250	300	200	150	250
V _{DS} (V)	V _{GS} (V)	I _D (A)	V _{GS(th)} min(V)	V _{GS(th)} max(V)	t _{on} typ (ns)	t _{off} typ (ns)	Q _G typ (nC)	ESD protection	R _{DS(on)} typ (mΩ) @ V _{gs} =											
									10 V	4.5 V	2.5 V	1.8 V								
12	8	5.7	0.4	-	23	67	10.1	-	-	28	-	39			PMN28UN					
20	8	6.3	2	4	23	71	10.6	-	-	23	-	37			PMN23UN					
		5.7	0.4	-	23	71	10.6	-	-	27	-	39			PMN27UN					
		5.7	0.45	-	20	66	7.4	-	-	30	-	44				PMV30UN ¹⁾				
		3.76	0.65	-	35	84	5.4	-	-	56	77	-				PMV56XN ¹⁾				
		2.5	0.65	-	35	84	5.4	-	-	56	77	-				SI2302DS				
		1.05	0.4	-	6.5	65	-	-	-	140	-	240				BSH105				
		2.28	0.45	0.95	14.5	23.5	0.89	-	-	250	-	420								PMZ250UN
		1	0.45	1	14.5	23.5	0.89	-	-	280	-	460					PMF280UN	PMR280UN		
	12	5.9	0.5	1.5	25	37	5.8	-	-	31	44	-				PMV31XN ¹⁾				
		2.15	0.5	1.5	16	17	0.72	-	-	270	440	-								PMZ270XN
		1	0.5	1.5	16	17	0.72	-	-	290	460	-					PMF290XN	PMR290XN		
	15	5.7	1	2	24	35	13.1	-	28	34	-	-			PMN34LN					
		4.1	1	2	24	35	13.1	-	55	70	-	-			PMN55LN					
30	8	4.9	0.45	-	22	60	9.9	-												

Small-signal MOSFETs single (N-channel) ≥ 50 V

types in **bold** represent new products

Package													SOT223 (SC-73)		SOT89 (SC-62)	SOT873	SOT23	SOT323 (SC-70)	SOT416 (SC-75)	SOT883 (SC-101)
																				
Size (mm)													6.5 x 3.5 x 1.65		4.5 x 2.5 x 1.5	3.3 x 3.3 x 0.85	2.9 x 1.3 x 1.0	2.0 x 1.25 x 0.95	1.6 x 0.8 x 0.77	1.0 x 0.6 x 0.5
P _{tot} (mW)													1700		1300	250	250	200	150	250
V _{DS} (V)	V _{GS} (V)	I _D (A)	V _{GS(th)} min(V)	V _{GS(th)} max(V)	t _{on} typ (ns)	t _{off} typ (ns)	Q _G typ (nC)	ESD protection	R _{DS(on)} typ (mΩ) @ V _{gs} =											
									10 V	4.5 V	2.5 V	1.8 V								
50	20	0.1	0.4	1.8	2	5	-	-	2800	3800 ³⁾	-	-					BSN20			
55	8	0.3	0.4	1.3	4	11	1	-	-	2300	2400	3100						BSH121		
	10	0.335	0.4	1.3	4	11	1	-	-	2300	2400	3100					BSH111			
	13	4.9	1	2	-	-	-	2KV	-	30	-	-	PHT11N06LT							
		3.5	1	2	-	-	-	2KV	-	65	-	-	PHT8N06LT							
		2.5	1	2	-	-	-	2KV	-	120	-	-	PHT6N06LT							
		2.5	2	4	-	-	-	2KV	120	-	-	-	PHT6N06T							
60	15	0.26	1	3.3	3	9	-	1KV	2800	3800	-	-						PMF3800SN		
		0.34	1	-	3	9	-	1KV	2800	3800	-	-					2N7002K			
		0.3	1	-	3	9	-	yes	2800	3800	-	-					BSH112			
		0.3	1	2.5	16	60	1.09	3KV	1100	1300	-	-					2N7002CK			
		0.3	1	2.5	tbd	tbd	tbd	-	2000 ²⁾	3000 ²⁾	-	-					2N7002P	2N7002PW	2N7002PT	2N7002PM
		0.3	1	2.5	tbd	tbd	tbd	2KV	1600 ²⁾	3000 ²⁾	-	-					2N7002BK	2N7002BKW	2N7002BKT	2N7002BKM
		0.57	1	-	6	7.2	-	-	780	1100	-	-						PMF780SN		

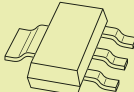
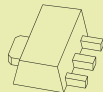
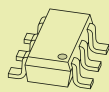
Small-signal MOSFETs dual (N-channel)

types in **bold** represent new products

Package														SOT363 (SC-88)	SOT666 (SC-88)
Size (mm)															
P _{tot} (mW)														300	300
V _{DS} (V)	V _{GS} (V)	I _D (A)	V _{GS(th)} min(V)	V _{GS(th)} max(V)	t _{on} typ (ns)	t _{off} typ (ns)	Q _G typ (nC)	ESD protection	R _{DSon} typ (mΩ) @ V _{gs} =						
									10 V	4.5 V	2.5 V	1.8 V			
20	8	0.87	0.45	1	14.5	23.5	-	-	-	280	-	460		PMGD280UN	
	12	0.86	0.5	1.5	16	17	0.72	-	-	290	460	-		PMGD290XN	
30	8	0.71	0.45	1	11.5	22.5	0.89	-	-	400	-	580		PMGD400UN	
	12	0.74	0.5	1.5	17	19.5	0.65	-	-	370	550	-		PMGD370XN	
	15	0.125	0.8	1.5	17	22	0.35	-	-	1800	2900	-		PMGD8000LN	
60	20	0.3	1	2.5	tbd	tbd	tbd	-	2000 ²⁾	3000 ²⁾	-	-		2N7002PS	2N7002PV
		0.3	1	2.5	tbd	tbd	tbd	2KV	1600 ²⁾	3000 ²⁾	-	-		2N7002BKS	2N7002BKV
		0.49	1	-	6	7.2	1.05	-	780	1100	-	-		PMGD780SN	

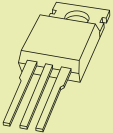
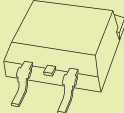
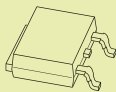
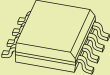
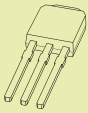
¹⁾ enhanced thermal capability ²⁾ max values

Small-signal MOSFETs single (P-channel)

Package														SOT223 (SC-73)	SOT89 (SC-62)	TSOP6 SOT457 (SC-74)	SOT23
Size (mm)																	
P _{tot} (mW)														1700	1300	600	250
V _{DS} (V)	V _{GS} (V)	I _D (A)	V _{GS(th)} min(V)	V _{GS(th)} max(V)	t _{on} typ (ns)	t _{off} typ (ns)	Q _G typ (nC)	ESD protection	R _{DSon} typ (mΩ) @ V _{gs} =								
									10 V	4.5 V	2.5 V	1.8 V					
12	8	1.52	0.4	-	6.5	65	-	-	-	80	-	140				BSH207	
		0.75	0.4	-	6.5	65	-	-	-	180	-	420					BSH205 ¹⁾
20	12	4.8	0.55	0.95	16	117	10	-	-	48	65	-				PMN50XP	</

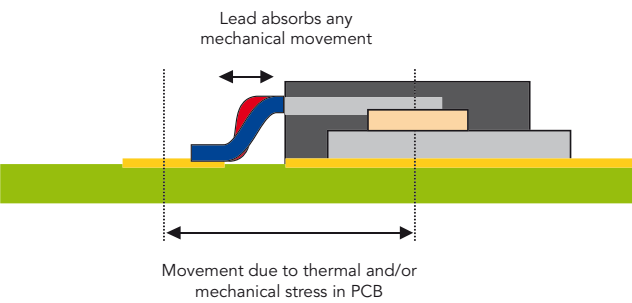
Power MOSFETs single (N-channel)

types in **bold** represent new products

V _{DS} (max) (V)	R _{DSon} (max) (mΩ) @ V _{gs} = 10 V	R _{DSon} (max) (mΩ) @ V _{gs} = 4.5 V	I _D (max) (A) @ 25 °C	Power-SO8 (LFPAK)	TO-220AB (SOT78)	D2PAK (SOT404)	DPAK (SOT428)		SO8 (SOT96-1)	IPAK (SOT533)
										
20	2.65	3.7	100	3.95 x 4.9 x 1.1	15.6 x 10 x 4.4	11 x 10 x 4.3	6 x 6.6 x 2.3		4.9 x 3.9 x 1.75	6 x 6.6 x 2.3
	-	2.7	100	PH3120L						
	-	5	32	PH2520U					PSMN006-20K	
	-	16 @ 5 V	44.7				PHD38N02LT			
	-	20 @ 5 V	10.9						PHKD6N02LT	
25	1.2	1.85	100	PSMN1R2-25YL						
	1.5	2.2	100	PSMN1R5-25YL						
	2.5	3.9	100	PH2525L						
	2.8	4.1	100	PH2625L						
	4	-	99	PH4025L						
	4.95	-	75				PHD96NQ03LT			
	5.5	8.2	81.7	PH5525L						
	5.8	-	75				PSMN005-25D			
	6	-	75				PHD108NQ03LT			
	6.3	9.5	78.7	PH6325L						
	6.3	10.6	75				PHD97NQ03LT			
	6.6	-	75							PHU97NQ03LT
	9	13	66	PH9025L						
	9	-	66.4				PHD78NQ03LT			PHU78NQ03LT
	9	-	61		PHP78NQ03LT					
	9.5	-	75				PHD77NQ03T			PHU77NQ03T
	10.5	-	66			PHB66NQ03LT	PHD66NQ03LT			
	-	3	100	PH2925U						

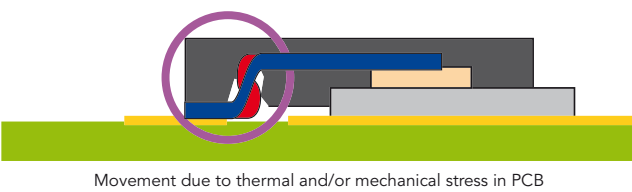
LFPAK for mechanical & thermal ruggedness

NXP LFPAK

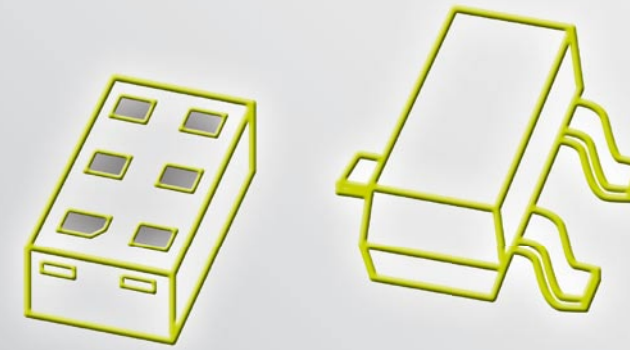


LFPAK pins provide compliance and allow for thermal expansion due to temperature difference between the MOSFET & PCB and also mechanical strain due to PCB bending & flexing

QFN Based Power-SO8



QFN sawn or micro-lead pins are fully encapsulated and do not allow for movement. Cracks in the mould compound can lead to moisture ingress & ionic contamination causing early failure of the MOSFET



Packages

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